

GP1M003A050HG

GP1M003A050HG Information

	Part Number	GP1M003A050HG	
100	Manufacturer	Global Power Technologies Group	
www.heisensc.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	ų
2. 14	Description	MOSFET N-CH 500V 2.5A TO220	. A
	Package	TO-220-3	
-		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Ree



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



GP1M003A050HG Specifications

Manufacturer Part Number	GP1M003A050HG
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-220-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	2.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	395pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	52.1W (Tc)
Rds On (Max) @ Id, Vgs	2.8 Ohm @ 1.25A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220
Package / Case	ТО-220-3
	Report errors?

GP1M003A050HG Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

GP1M003A050HG Payment Methods





If you have any question about GP1M003A050HG, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com